

PS9001

HIGH CMR, 10 Mbps OPEN COLLECTOR OUTPUT TYPE, 5-PIN SOP (LSO5 WITH 8mm CREEPAGE DISTANCE) PHOTOCOUPLER

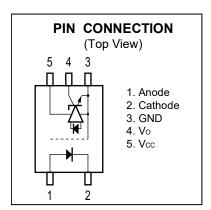
R08DS0130EJ0101 Rev.1.01 Oct 29, 2018

DESCRIPTION

The PS9001 is an optically coupled high-speed, active low type isolator containing an AlGaAs LED on the input side and a photodiode and a signal processing circuit on the output side on one chip.

FEATURES

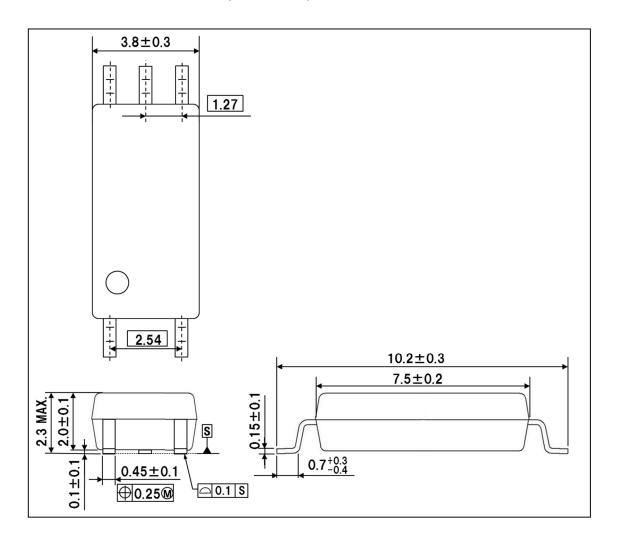
- Long creepage distance (8 mm MIN)
- High common mode transient immunity (CM_H, CM_L = ± 50 kV/ μ s MIN.)
- Operating Ambient Temperature (125 °C MAX.)
- High-speed response (t_{PHL} = 100 ns MAX., t_{PLH} = 100 ns MAX.)
- Embossed tape product : PS9001-F3: 3000 pcs/reel
- Pb-Free product
- Safety standards
 - UL approved: UL1577, Double protection
 - CSA approved: CAN/CSA-C22.2 No. 62368-1, Reinforced insulation
 - VDE approved: DIN EN 60747-5-5 (Option)



APPLICATIONS

- Measurement equipment
- FA Network

PACKAGE DIMENSIONS (UNIT: mm)

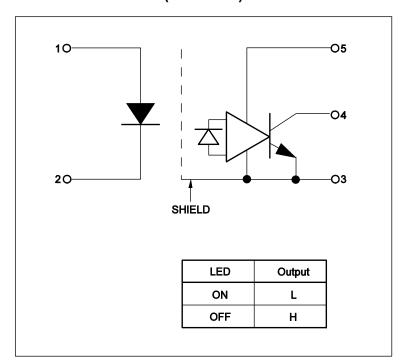


Weight: 0.119g (typ.)

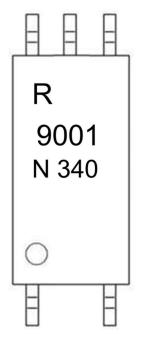
PHOTOCOUPLER CONSTRUCTION

Parameter	MIN.
Air Distance	8.0 mm
Creepage Distance	8.0 mm
Isolation Distance	0.15 mm

BLOCK DIAGRAM (Unit: mm)



MARKING EXAMPLE



R		An in	An initial of "Renesas"		
9001 Produ		Prod	uct Part Number		
0		No.1	No.1 pin Mark, Anode Mark		
N340	N	Rank	Rank Code		
	340	Assembly Lot			
		3	3 Last one-digit of Assembly Year		
		40	Weekly Serial Code		

ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS9001	PS9001-Y-AX	Pb-Free and	20 pcs (Tape 20 pcs cut)	Standard products	PS9001
PS9001-F3	PS9001-Y-F3-AX	Halogen Free (Ni/Pd/Au)	Embossed Tape 3 000 pcs/reel	(UL, CSA approved)	
PS9001-V	PS9001-Y-V-AX		20 pcs (Tape 20 pcs cut)	UL, CSA,	
PS9001-V-F3	PS9001-Y-V-F3-AX		Embossed Tape 3 000	DIN EN 60747-5-5	
			pcs/reel	approved	

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current*1	lF	25	mA
	Reverse Voltage	V _R	5	V
Detector	Supply Voltage	Vcc	-0.5 to 7	\ \
	Output Voltage	Vo	-0.5 to 7	V
	Output Current	lo	20	mA
	Power Dissipation	Pc	100	mW
Isolation Volt	age *2	BV	5000	Vr.m.s.
Operating An	nbient Temperature	TA	-40 to +125	°C
Storage Tem	perature	T _{stg}	−55 to +150	°C

Notes: *1. Reduced to 0.325 mA/ $^{\circ}$ C at T_A = 85 $^{\circ}$ C or more.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
High Level Input Voltage	VF	-2	_	0.8	V
Low Level Input Current	I _F	8	10	12	mA
Supply Voltage	Vcc	4.5	5.0	5.5	V
Operating Ambient Temperature	T _A	-40	-	125	°C

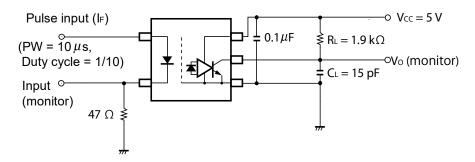
^{*2.} AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-2 shorted together, 3-5 shorted together.

ELECTRICAL CHARACTERISTICS (T_A = -40 to +125°C, Vcc=5V unless otherwise specified)

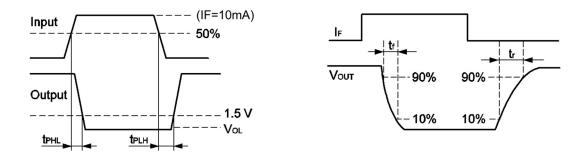
	Parameter	Symbol	Conditions	MIN.	TYP. *1	MAX.	Unit
Diode	Forward Voltage	V _F	I _F = 10 mA, T _A = 25°C	1.35	1.56	1.75	V
	Reverse Current	I _R	V _R = 3 V, T _A = 25°C			10	μА
	Terminal Capacitance	Ct	f = 1 MHz, V _F = 0 V, T _A = 25°C		30		pF
Detector	High Level Output Current	Іон	$V_{CC} = V_O = 5.5 \text{ V}, V_F = 0.8 \text{ V}$			50	μA
	Low Level Output Voltage	V _{OL}	I _F = 4 mA, I _{OL} = 5 mA		0.1	0.6	V
	High Level Supply Current	Іссн	$V_{CC} = 5.5 \text{ V}, I_F = 0 \text{ mA}, V_0 = \text{open}$		1.4	2.0	mA
	Low Level Supply Current	Iccl	$V_{CC} = 5.5 \text{ V}, I_F = 10\text{mA}, V_O = \text{open}$		1.4	2.0	mA
Coupled	Threshold Input Voltage $(H \rightarrow L)$	I _{FHL}	V _O = 0.6V,I _O = 5mA		1.2	4.0	mA
	Propagation Delay Time $(H \rightarrow L)^{*2}$	t _{PHL}	I _F = 10 mA, R _L = 1.9 k Ω , C _L = 15 pF, V _{THHL} = 1.5 V, V _{THLH} = 1.5 V		35	100	ns
	Propagation Delay Time $(L \rightarrow H)^{*2}$	t _{PLH}			65	100	ns
	Pulse Width Distortion (PWD)	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1			30	50	ns
	Propagation Delay Skew	t _{psk}				60	ns
	Common Mode Transient Immunity at High Level Output *3	СМн	$T_A = 25^{\circ}\text{C},$ $I_F = 0 \text{ mA}, V_O > 1.5 \text{ V},$ $R_L = 1.9 \text{ k}\Omega, V_{CM} = 1.5 \text{ kV},$ $C_L = 15 \text{ pF}$	50			kV/μs
	Common Mode Transient Immunity at Low Level Output *3	CM _L	$T_{A} = 25^{\circ}C,$ $I_{F} = 10 \text{ mA, V}_{O} < 1.5 \text{ V},$ $R_{L} = 1.9 \text{ k}\Omega, V_{CM} = 1.5 \text{ kV},$ $C_{L} = 15 \text{ pF}$	50			kV/μs

Notes: *1. Typical values at $T_A = 25$ °C

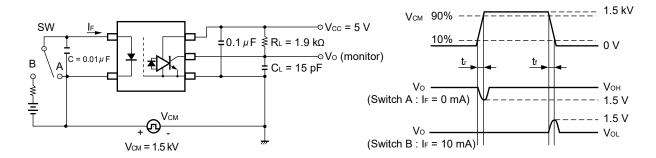
*2. Test circuit for tPHL and tPLH



Remark C_L includes probe and stray wiring capacitance.

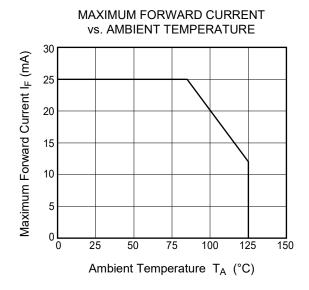


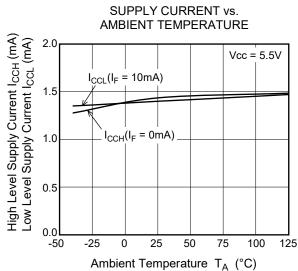
*3. Test circuit for common mode transient immunity

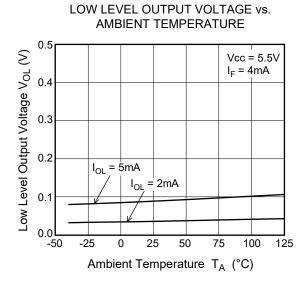


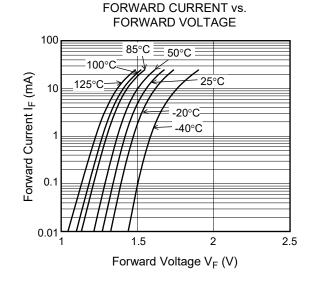
Remark C_L includes probe and stray wiring capacitance.

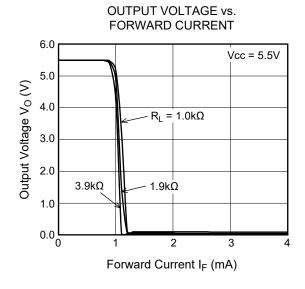
TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

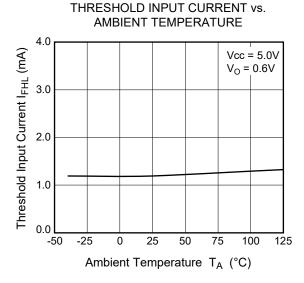






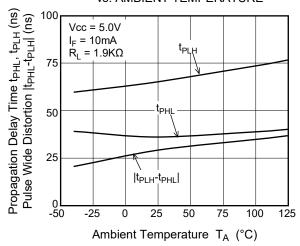




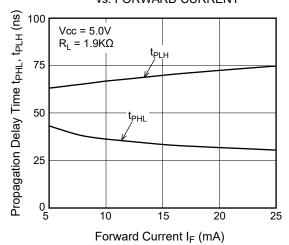


Remark The graphs indicate nominal characteristics.

PROPAGATION DELAY TIME, PULSE WIDE DISTORTION vs. AMBIENT TEMPERATURE

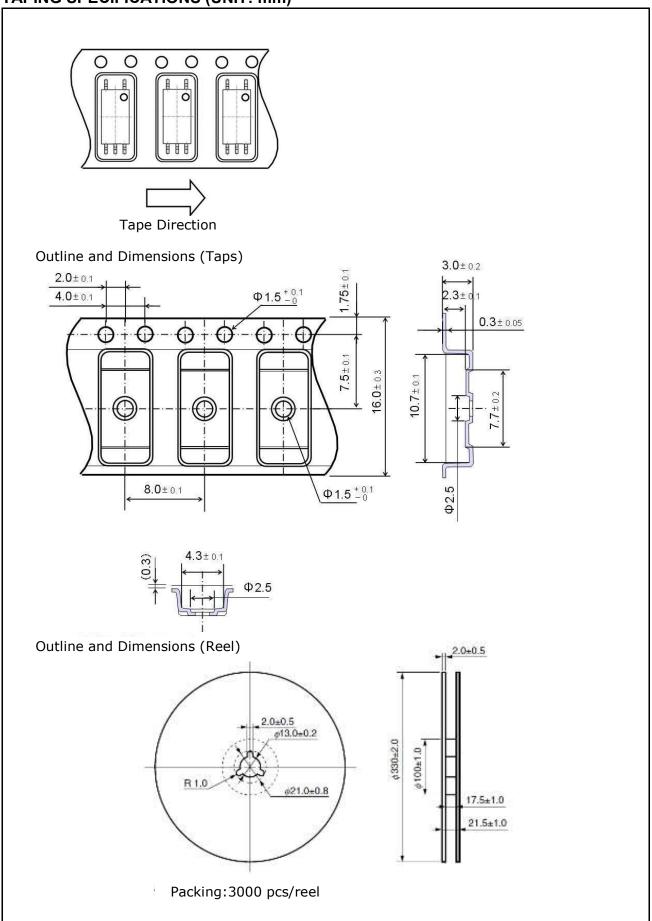


PROPAGATION DELAY TIME vs. FORWARD CURRENT

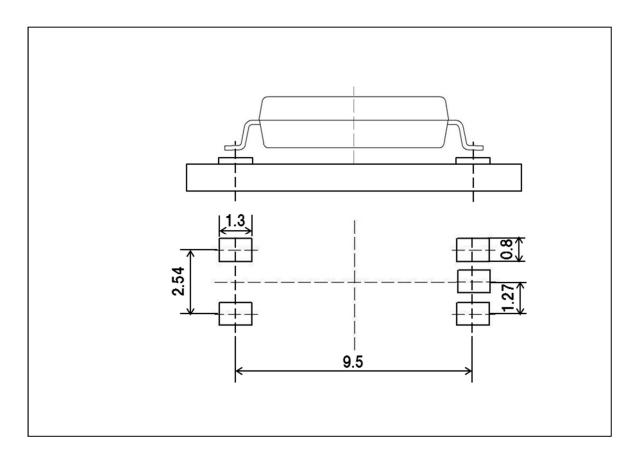


Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)



RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

NOTES ON HANDLING

- 1. Recommended soldering conditions
 - (1) Infrared reflow soldering

Peak reflow temperature 260°C or below (package surface temperature)

Time of peak reflow temperature 10 seconds or less Time of temperature higher than 220°C 60 seconds or less

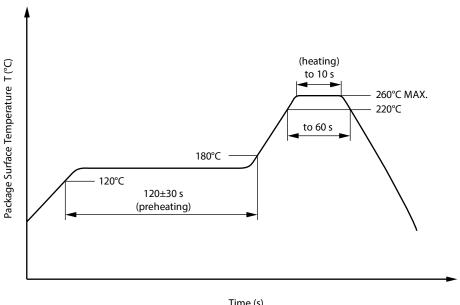
120±30 s Time to preheat temperature from 120 to 180°C Number of reflows Three

Flux Rosin flux containing small amount of chlorine (The flux

with a maximum chlorine content of 0.2 Wt% is

recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

Temperature 260°C or below (molten solder temperature)

Time 10 seconds or less

Preheating conditions 120°C or below (package surface temperature)

Number of times One (Allowed to be dipped in solder including plastic mold portion.)

Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

Peak Temperature (lead part temperature) 350°C or below

Time (each pins) 3 seconds or less

Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(4) Cautions

 Fluxes Avoid removing the residual flux with freon-based and halogens-based (chlorine-based) cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

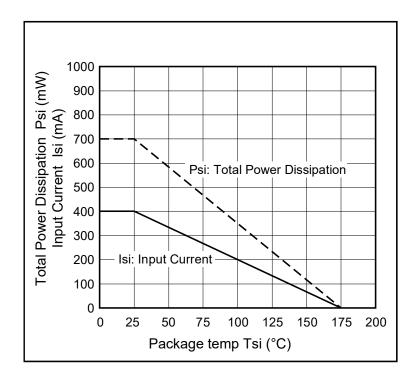
USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of more than $0.1~\mu\text{F}$ is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10~mm.
- 3. Avoid storage at a high temperature and high humidity.
- 4. Do not use adhesives or coating materials including halogens to fix this device.

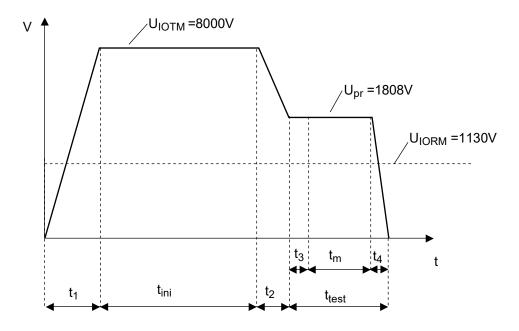
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength			
maximum operating isolation voltage	U_IORM	1 130	V_{peak}
Test voltage (partial discharge test, procedure a for type test and random test)	U_pr	1 808	V_{peak}
$U_{pr} = 1.6 \times U_{IORM.}, P_d < 5 pC$			
Test voltage (partial discharge test, procedure b for all devices)	U_pr	2 119	V_{peak}
$U_{pr} = 1.875 \times U_{IORM.}, P_d < 5 pC$			
Highest permissible overvoltage	U _{TR}	8 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	400	
Material group (DIN EN 60664-1 VDE0110 Part 1)		П	
Storage temperature range	T _{stg}	-55 to +150	°C
Operating temperature range	TA	-40 to +125	°C
Isolation resistance, minimum value			
V _{IO} = 500 V dc at T _A = 25°C	Ris MIN.	10 ¹²	Ω
V _{IO} = 500 V dc at T _A MAX. at least 100°C	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal			
derating curve)			
Package temperature	Tsi	175	°C
Current (input current I _F , Psi = 0)	lsi	400	mA
Power (output or total power dissipation)	Psi	700	mW
Isolation resistance			
V _{IO} = 500 V dc at T _A = Tsi	Ris MIN.	10 ⁹	Ω

Dependence of maximum safety ratings with package temperature



Method a) Destructive Test, Type and Sample Test



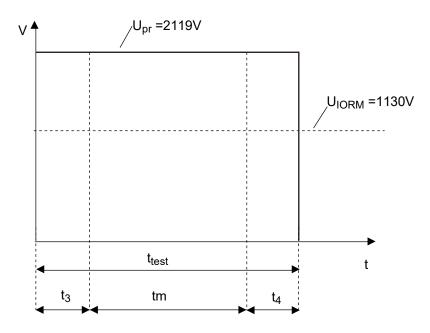
 $t_1, t_2 = 1 \text{ to } 10 \text{ sec}$

 $t_3, t_4 = 1 \text{ sec}$

 $t_{m(PARTIAL\ DISCHARGE)}$ = 10 sec

 $t_{\text{test}} = 12 \text{ sec}$ $t_{\text{ini}} = 60 \text{ sec}$

Method b) Non-destructive Test, 100% Production Test



 $t_3, t_4 = 0.1 \text{ sec}$

 $t_{m(PARTIAL\ DISCHARGE)} = 1.0\ sec$

 $t_{test} = 1.2 sec$

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

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